

Converting micro-sized kerf-loss silicon waste to high-performance hollow-structured silicon/carbon composite anodes for lithium-ion batteries

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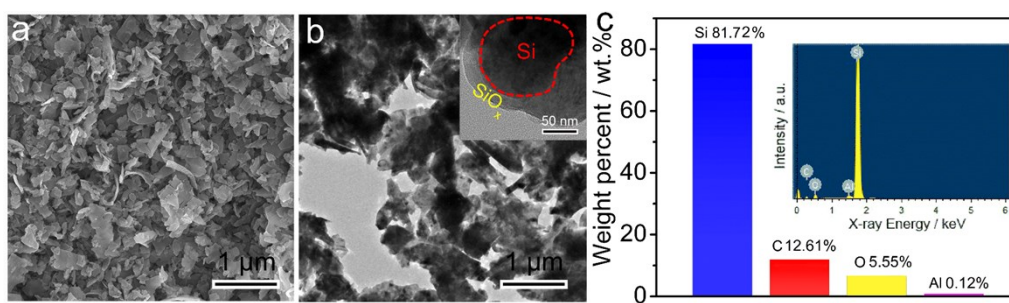


Fig. S1 (a) SEM and (b) TEM images of KL-Si. (c) EDS analysis with displaying weight percent of elements in the KL-Si.

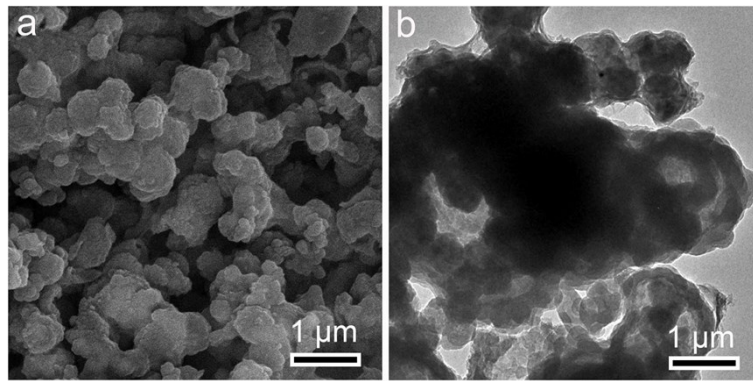


Fig. S2 (a) SEM and (b) TEM images of KL-Si@C

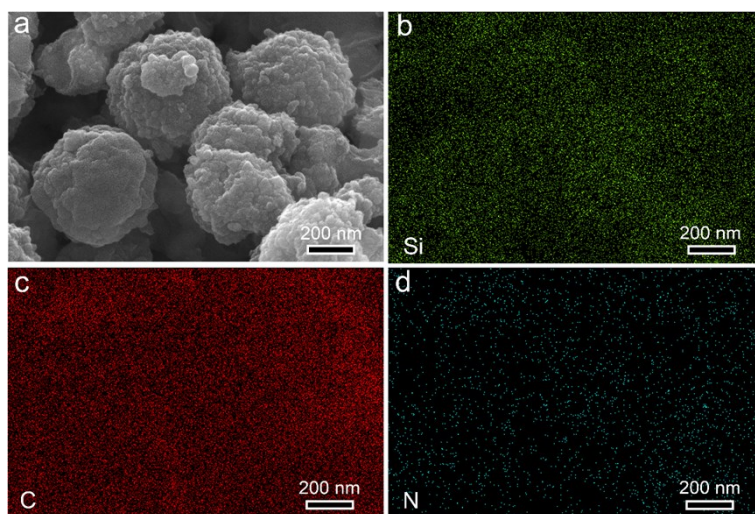


Fig. S3 (a) SEM image Si@void@C, corresponding Si (b), C (c), N (d) elemental mapping images.

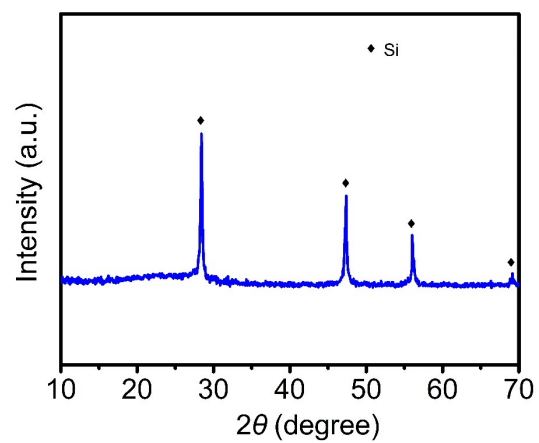


Fig. S4 XRD pattern of after etching KL-Si in HF solution.

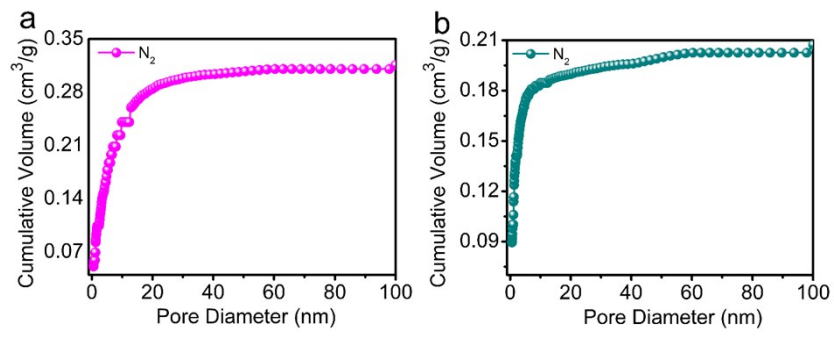


Fig. S5 Cumulative-desorption pore volume distribution curves of (a) Si@void@C, and (b)

KL-Si@C.

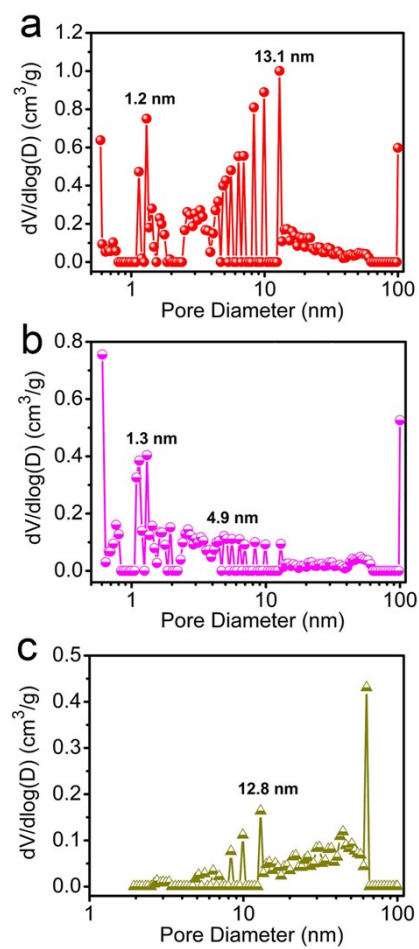


Fig. S6 Pore size distribution of the (a) Si@void@C, (b) KL-Si@C, and (c) KL-Si.

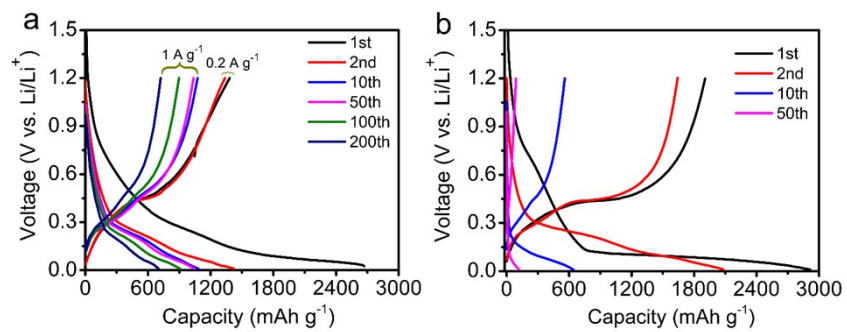


Fig. S7 Galvanostatic charge/discharge profiles of (a) KL-Si@C and (b) KL-Si at each current density from 0.2 to 1 A g⁻¹, respectively.

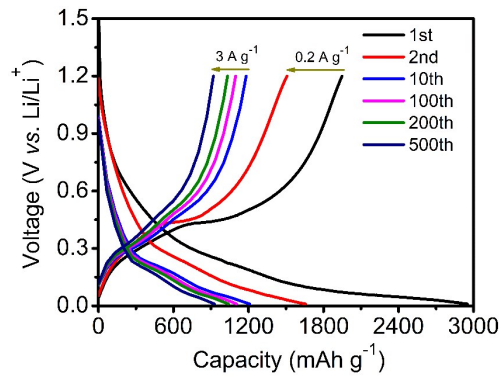


Fig. S8 Galvanostatic charge/discharge profile of Si@void@C at each current density from 0.2 to 3 A g⁻¹.

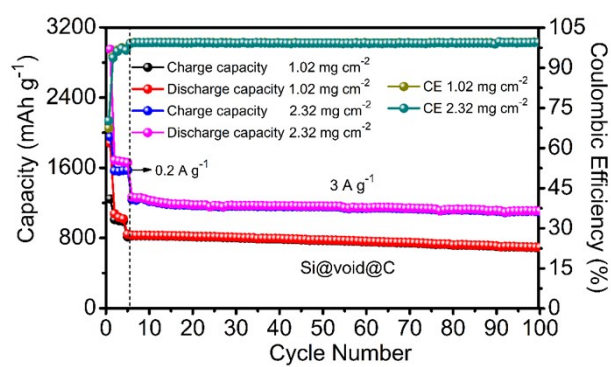


Fig. S9 Discharge capacities *vs.* cycling number of the Si@void@C anode with different mass loadings at 3 A g⁻¹ (the initial three cycles are carried out at 0.2 A g⁻¹).

Table S1. Surface areas and pore structures of KL-Si, KL-Si@C, and Si@void@C

Samples	BET analysis						
	S_{BET}	$S_{\text{micro}}^{\text{a}}$	$S_{\text{meso}}^{\text{b}}$	$V_{\text{total}}^{\text{c}}$	$V_{\text{micro}}^{\text{d}}$	$V_{\text{meso}}^{\text{e}}$	D_{aver}
	($\text{m}^2 \text{g}^{-1}$)	($\text{m}^2 \text{g}^{-1}$)	($\text{m}^2 \text{g}^{-1}$)	($\text{cm}^3 \text{g}^{-1}$)	($\text{cm}^3 \text{g}^{-1}$)	($\text{cm}^3 \text{g}^{-1}$)	(nm)
KL-Si	19.11	3.48	13.07	0.07	0.002	0.067	14.6
KL-Si@C	317.29	208.88	94.35	0.21	0.11	0.099	2.6
Si@void@C	333.25	116.29	176.26	0.33	0.06	0.26	4.2

^a S_{micro} is the surface area of the micropores. ^b S_{meso} is the surface area of the mesopores. ^c V_{total} is the total pore volume. ^d V_{micro} is the volume of the micropores. ^e V_{meso} is the volume of the mesopores.

Table S2. Equivalent series resistance (R_e) and charge transfer resistance (R_{ct}) of the KL-Si, KL-Si@C, and Si@void@C.

Samples	R_e (Ω)	R_{ct} (Ω)
KL-Si	10.37	117.73
KL-Si@C	9.18	75.02
Si@void@C	8.41	56.31

Table S3. Comparison of the electrochemical performance of the as-prepared samples with other Si-based anode materials for lithium-ion battery.

Materials	Si content	Tests done at/Initial discharge specific capacity	Cycling performance	Ref.
			Tests done at/Cycle number/Specific capacity	
Core-shell structured nano-Si/C	81 wt.%	0.1 (A g ⁻¹)/~2300 mAh g ⁻¹	0.1 (A g ⁻¹)/50/~1800 mAh g ⁻¹	1
Micro-nano Si/SiO _x /PAN	80 wt.%	0.1 (A g ⁻¹)/2734 mAh g ⁻¹	0.1 (A g ⁻¹)/100/988 mAh g ⁻¹	2
Nanoarchitecture Si/C	87 wt.%	0.12 (A g ⁻¹)/2505 mAh g ⁻¹	1.2 (A g ⁻¹)/500/1150 mAh g ⁻¹	3
Mesoporous Si@C microspheres	32 wt.%	0.05 (A g ⁻¹)/1637 mAh g ⁻¹	0.05 (A g ⁻¹)/100/1053 mAh g ⁻¹	4
yolk-shell structure Si/C	71 wt.%	0.4 (A g ⁻¹)/2833 mAh g ⁻¹	0.4 (A g ⁻¹)/50/~2000 mAh g ⁻¹	5
core-shell Si/C fibers	22 wt.%	0.2 (A g ⁻¹)/~1600 mAh g ⁻¹	0.5 (A g ⁻¹)/300/603 mAh g ⁻¹	[6]
Core-shell fibers Si/C	50 wt.%	0.12 (A g ⁻¹)/1500 mAh g ⁻¹	2.75 (A g ⁻¹)/300/750 mAh g ⁻¹	7
Yolk-Shell Porous Si@C	65 wt.%	0.2 (A/g)/1876 mAh g ⁻¹	1 (A g ⁻¹)/600/600 mAh g ⁻¹	8
Hollow core-shell structured Si/C	37 wt.%	0.1 (A g ⁻¹)/1370 mAh g ⁻¹	0.1 (A g ⁻¹)/100/783 mAh g ⁻¹	9
Porous Si with N-doped carbon	49 wt.%	0.2 (A g ⁻¹)/1612 mAh g ⁻¹	0.2 (A g ⁻¹)/200/750 mAh g ⁻¹	10
Si/mesoporous carbon	10 wt.%	0.2 (A g ⁻¹)/1362 mAh g ⁻¹	0.2(A g ⁻¹)/100/581 mAh g ⁻¹	11
Mesoporous C/Si composite	76 wt.%	0.2 (A g ⁻¹)/~2700 mAh g ⁻¹	0.5(A g ⁻¹)/100/1018 mAh g ⁻¹	12
Porous Si/C microspheres	44 wt.%	0.2 (A g ⁻¹)/~1500 mAh g ⁻¹	0.2(A g ⁻¹)/100/~530 mAh g ⁻¹	13
Si@void@C	43 wt.%	0.2 (A g ⁻¹)/2710 mAh g ⁻¹	1 (A g ⁻¹)/300/1164.4 mAh g ⁻¹ 3 (A g ⁻¹)/500/927 mAh g ⁻¹	This work

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